

(19) World Intellectual Property
Organization
International Bureau



(43) International Publication Date
14 April 2005 (14.04.2005)

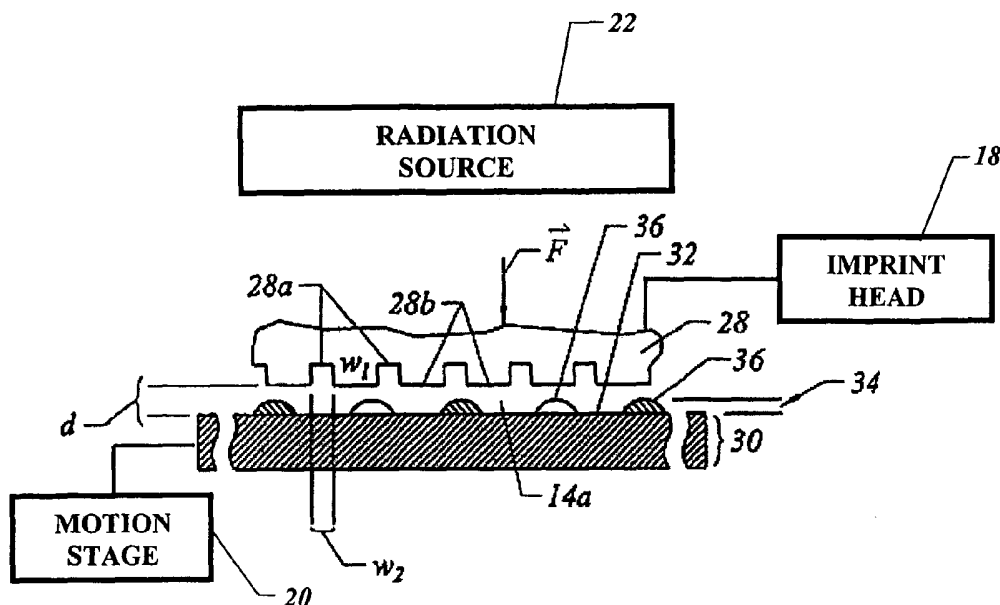
PCT

(10) International Publication Number
WO 2005/033797 A2

- (51) International Patent Classification⁷: **G03F** (72) Inventors: **MCMACKIN, Ian, M.**; 7700 North Capital of Texas Highway #817, Austin, TX 78731 (US). **BABBS, Daniel, A.**; 2008 Mistywood Drive, Austin, TX 78746 (US). **VOTH, Duane, J.**; 14000 Renaissance Court #3010, Austin, TX 78728 (US). **WATTS, Michael, P. C.**; 9404 Bell Mountain Drive, Austin, TX 78730 (US). **TRUSKETT, Van, N.**; 4604 Beechwood Hollow, Austin, TX 78731 (US). **XU, Frank, Y.**; 3814 Harvey Penick Dr., Round Rock, TX 78664 (US). **VOISIN, Ronald, D.**; 10050 Great Hills Drive #509, Austin, TX 78759 (US). **LAD, Pankaj, B.**; 2920 Thrushwood Drive, Ste. A, Austin, TX 78757 (US).
- (21) International Application Number: PCT/US2004/031408
- (22) International Filing Date: 24 September 2004 (24.09.2004)
- (25) Filing Language: English
- (26) Publication Language: English
- (30) Priority Data: 10/677,639 2 October 2003 (02.10.2003) US
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- (81) Designated States (unless otherwise indicated, for every kind of national protection available): AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG,

[Continued on next page]

(54) Title: SINGLE PHASE FLUID IMPRINT LITHOGRAPHY METHOD



(57) Abstract: The present invention is directed toward a method for reducing pattern distortions in imprinting layers by reducing gas pockets present in a layer of viscous liquid deposited on a substrate. To that end, the method includes varying the transport of gases disposed proximate to the viscous liquid. Specifically, the atmosphere proximate to the substrate wherein a pattern is to be recorded is saturated with gases that are either highly soluble, highly diffusive, or both with respect to the viscous liquid being deposited. Additionally, or in lieu of saturating the atmosphere, the pressure of the atmosphere may be reduced.



PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM,
TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM,
ZW.

SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ,
GW, ML, MR, NE, SN, TD, TG).

(84) Designated States (*unless otherwise indicated, for every kind of regional protection available*): ARIPO (BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PL, PT, RO, SE, SI,

Published:

— without international search report and to be republished upon receipt of that report

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SINGLE PHASE FLUID IMPRINT LITHOGRAPHY METHOD

BACKGROUND OF THE INVENTION

[0001] The field of invention relates generally to imprint lithography. More particularly, the present invention is directed to reducing pattern distortions during imprint lithography processes by reducing, if not eliminating, the presence of gases in imprinting layers.

[0002] Micro-fabrication involves the fabrication of very small structures, e.g., having features on the order of micro-meters or smaller. One area in which micro-fabrication has had a sizeable impact is in the processing of integrated circuits. As the semiconductor processing industry continues to strive for larger production yields while increasing the circuits per unit area formed on a substrate, micro-fabrication becomes increasingly important. Micro-fabrication provides greater process control while reducing the minimum feature dimension of the structures formed. Other areas of development in which micro-fabrication has been employed include biotechnology, optical technology, mechanical systems and the like.

[0003] An exemplary micro-fabrication technique is shown in United States patent number 6,334,960 to Willson et al. Willson et al. disclose a method of forming a relief image in a structure. The method includes providing a substrate having a transfer layer. The transfer layer is covered with a polymerizable fluid composition. A mold makes mechanical contact with the polymerizable fluid. The mold includes a relief structure, and the polymerizable fluid composition fills the relief structure. The polymerizable fluid

composition is then subjected to conditions to solidify and polymerize the same, forming a solidified polymeric material on the transfer layer that contains a relief structure complimentary to that of the mold. The mold is then separated from the solid polymeric material such that a replica of the relief structure in the mold is formed in the solidified polymeric material. The transfer layer and the solidified polymeric material are subjected to an environment to selectively etch the transfer layer relative to the solidified polymeric material such that a relief image is formed in the transfer layer. The time required and the minimum feature dimension provided by this technique is dependent upon, *inter alia*, the composition of the polymerizable material.

[0004] United States patent number 5,772,905 to Chou discloses a lithographic method and apparatus for creating ultra-fine (sub-25 nm) patterns in a thin film coated on a substrate in which a mold having at least one protruding feature is pressed into a thin film carried on a substrate. The protruding feature in the mold creates a recess of the thin film. The mold is removed from the film. The thin film then is processed such that the thin film in the recess is removed, exposing the underlying substrate. Thus, patterns in the mold are replicated in the thin film, completing the lithography. The patterns in the thin film will be, in subsequent processes, reproduced in the substrate or in another material which is added onto the substrate.

[0005] Yet another imprint lithography technique is disclosed by Chou et al. in Ultrafast and Direct Imprint of Nanostructures in Silicon, Nature, Vol. 417, pp. 835-

837, June 2002, which is referred to as a laser assisted direct imprinting (LADI) process. In this process, a region of a substrate is made flowable, e.g., liquefied, by heating the region with the laser. After the region has reached a desired viscosity, a mold, having a pattern thereon, is placed in contact with the region. The flowable region conforms to the profile of the pattern and is then cooled, solidifying the pattern into the substrate. A concern with the above techniques involves pattern distortions attributable to the presence of atmosphere proximate to the flowable region.

[0006] It is desired, therefore, to provide a system to reduce distortions in patterns formed using imprint lithographic techniques.

SUMMARY OF THE INVENTION

[0007] The present invention is directed to a method to reduce pattern distortions by substantially reducing gas pockets present in a layer of viscous liquid deposited on a substrate. To that end, the method includes dispensing gases, proximate to the mold, with varied transport properties in the viscous liquid. Specifically, the atmosphere proximate to the substrate is saturated with gases that are either highly soluble, highly diffusive, or both with respect to the viscous liquid being deposited. Additionally, or in lieu of providing the atmosphere described above, the pressure of the atmosphere may be reduced. Use of these methods facilitates the rapid fabrication of distortion-free imprints. These and other embodiments are described more fully below.

BRIEF DESCRIPTION OF THE DRAWINGS

- [0008] Fig. 1 is a perspective view of a lithographic system in accordance with the present invention;
- [0009] Fig. 2 is a simplified elevation view of a lithographic system shown in Fig. 1;
- [0010] Fig. 3 is a simplified representation of material from which an imprinting layer, shown in Fig. 2, is comprised before being polymerized and cross-linked;
- [0011] Fig. 4 is a simplified representation of cross-linked polymer material into which the material shown in Fig. 3 is transformed after being subjected to radiation;
- [0012] Fig. 5 is a simplified elevation view of a mold spaced-apart from the imprinting layer, shown in Fig. 1, after patterning of the imprinting layer;
- [0013] Fig. 6 is a simplified elevation view of an additional imprinting layer positioned atop the substrate shown in Fig. 5 after the pattern in the first imprinting layer is transferred therein;
- [0014] Fig. 7 is a detailed perspective view of a print head shown in Fig. 1;
- [0015] Fig. 8 is a cross-sectional view of a chucking system in accordance with the present invention;
- [0016] Fig. 9 is detailed cross-sectional view of an imprint head shown in Fig. 7; and
- [0017] Fig. 10 is a bottom-up perspective view of the imprint head shown in Fig. 9.

DETAILED DESCRIPTION OF THE INVENTION

- [0018] Fig. 1 depicts a lithographic system 10 in accordance with one embodiment of the present invention that includes a pair of spaced-apart bridge supports 12 having a bridge 14 and a stage support 16 extending therebetween. Bridge 14 and stage support 16 are spaced-

apart. Coupled to bridge 14 is an imprint head 18, which extends from bridge 14 toward stage support 16 and provides movement along the Z-axis. Disposed upon stage support 16 to face imprint head 18 is a motion stage 20. Motion stage 20 is configured to move with respect to stage support 16 along X- and Y-axes. It should be understood that imprint head 18 may provide movement along the X- and Y-axes, as well as in the Z-axis, and motion stage 20 may provide movement in the Z-axis, as well as in the X and Y axes. An exemplary motion stage device is disclosed in United States patent application number 10/194,414, filed July 11, 2002, entitled "Step and Repeat Imprint Lithography Systems," assigned to the assignee of the present invention, and which is incorporated by reference herein in its entirety. A radiation source 22 is coupled to lithographic system 10 to impinge actinic radiation upon motion stage 20. As shown, radiation source 22 is coupled to bridge 14 and includes a power generator 23 connected to radiation source 22. Operation of lithographic system 10 is typically controlled by a processor 25 that is in data communication therewith.

[0019] Referring to both Figs. 1 and 2, connected to imprint head 18 is a template 26 having a mold 28 thereon. Mold 28 includes a plurality of features defined by a plurality of spaced-apart recessions 28a and protrusions 28b. The plurality of features defines an original pattern that is to be transferred into a substrate 30 positioned on motion stage 20. To that end, imprint head 18 and/or motion stage 20 may vary a distance "d" between mold 28 and substrate 30. In this manner, the features on mold 28 may be imprinted into a

flowable region of substrate 30, discussed more fully below. Radiation source 22 is located so that mold 28 is positioned between radiation source 22 and substrate 30. As a result, mold 28 is fabricated from material that allows it to be substantially transparent to the radiation produced by radiation source 22.

[0020] Referring to both Figs. 2 and 3, a flowable region, such as an imprinting layer 34, is disposed on a portion of a surface 32 that presents a substantially planar profile. A flowable region may be formed using any known technique, such as a hot embossing process disclosed in United States patent number 5,772,905, which is incorporated by reference in its entirety herein, or a laser assisted direct imprinting (LADI) process of the type described by Chou et al. in Ultrafast and Direct Imprint of Nanostructures in Silicon, Nature, Col. 417, pp. 835-837, June 2002. Further, the flowable region may also comprise a spin-coated film of viscous fluid that may be molded and cured to form a rigid replica. In the present embodiment, however, a flowable region consists of imprinting layer 34 being deposited as a plurality of spaced-apart discrete droplets 36 of a material 36a on substrate 30, discussed more fully below. An exemplary system for depositing droplets 36 is disclosed in United States patent application number 10/191,749, filed July 9, 2002, entitled "System and Method for Dispensing Liquids," assigned to the assignee of the present invention, and which is incorporated by reference herein in its entirety. Imprinting layer 34 is formed from material 36a that may be selectively polymerized and cross-linked to record the original pattern therein, defining a recorded pattern. An exemplary composition

for material 36a is disclosed in United States patent application number 10/463,396, filed June 16, 2003, and entitled "Method to Reduce Adhesion Between a Conformable Region and a Pattern of a Mold," which is incorporated by reference in its entirety herein. Material 36a is shown in Fig. 4 as being cross-linked at points 36b, forming a cross-linked polymer material 36c.

[0021] Referring to Figs. 2, 3 and 5, the pattern recorded in imprinting layer 34 is produced, in part, by mechanical contact with mold 28. To that end, distance "d" is reduced to allow droplets 36 to come into mechanical contact with mold 28, spreading droplets 36 so as to form imprinting layer 34 with a contiguous formation of material 36a over surface 32. In one embodiment, distance "d" is reduced to allow sub-portions 34a of imprinting layer 34 to ingress into and fill recessions 28a.

[0022] To facilitate filling of recessions 28a, material 36a is provided with the requisite properties to completely fill recessions 28a, while covering surface 32 with a contiguous formation of material 36a. In the present embodiment, sub-portions 34b of imprinting layer 34 in superimposition with protrusions 28b remain after the desired, usually minimum, distance "d" has been reached, leaving sub-portions 34a with a thickness t_1 , and sub-portions 34b with a thickness, t_2 . Thicknesses " t_1 " and " t_2 " may be any thickness desired, dependent upon the application. Typically, t_1 is selected so as to be no greater than twice the width u of sub-portions 34a, i.e., $t_1 \leq 2u$, shown more clearly in Fig. 5.

[0023] Referring to Figs. 2, 3 and 4, after a desired distance "d" has been reached, radiation source 22

produces actinic radiation that polymerizes and cross-links material 36a, forming cross-linked polymer material 36c. As a result, the composition of imprinting layer 34 transforms from material 36a to cross-linked polymer material 36c, which is a solid. Specifically, cross-linked polymer material 36c is solidified to provide side 34c of imprinting layer 34 with a shape conforming to a shape of a surface 28c of mold 28, shown more clearly in Fig. 5. After imprinting layer 34 is transformed to consist of cross-linked polymer material 36c, shown in Fig. 4, imprint head 18, shown in Fig. 2, is moved to increase distance "d" so that mold 28 and imprinting layer 34 are spaced-apart.

[0024] Referring to Fig. 5, additional processing may be employed to complete the patterning of substrate 30. For example, imprinting layer 34 and substrate 30 may be etched to transfer the pattern of imprinting layer 34 into substrate 30, providing a patterned surface 32a, shown in Fig. 6. To facilitate etching, the material from which imprinting layer 34 is formed may be varied to define a relative etch rate with respect to substrate 30, as desired. The relative etch rate of imprinting layer 34 and substrate 30 may be between about 1.5:1 to about 100:1.

[0025] Alternatively, or additionally, imprinting layer 34 may be provided with an etch differential with respect to photo-resist material (not shown) selectively disposed thereon. The photo-resist material (not shown) may be provided to further pattern imprinting layer 34, using known techniques. Any etch process may be employed, dependent upon the etch rate desired and the underlying constituents that form substrate 30 and

imprinting layer 34. Exemplary etch processes may include plasma etching, reactive ion etching, chemical wet etching and the like.

[0026] Referring to Figs. 7 and 8, template 26, upon which mold 28 is present, is coupled to an imprint head housing 18a via a chucking system 40 that includes a chuck body 42. Chuck body 42 is adapted to retain template 26 upon which mold 28 is attached employing vacuum techniques. To that end, chuck body 42 includes one or more recesses 42a that are in fluid communication with a pressure control system, such as a fluid supply system 70. Fluid supply system 70 may include one or more pumps to provide both positive and negative pressure, as well as a supply of fluid to facilitate reducing, if not preventing, trapping of gases, such as air, in imprinting layer 34, shown in Fig. 5. An exemplary chucking system is disclosed in United States patent application number 10/293,224, entitled "Chucking System For Modulating Shapes of Substrates," assigned to the assignee of the present invention, and which is incorporated by reference in its entirety herein.

[0027] As discussed above, during imprinting template 26 and, therefore, mold 28 are brought into proximity with substrate 30 before patterning imprinting material 36a, disposed on a region 77. Specifically, template 26 is brought within tens of microns of substrate 30, e.g., 15 microns more or less. It has been found desirable to perform localized control of the atmosphere 78 that is proximate to both template 26 and region 77. For example, to avoid the deleterious effects of gases and/or gas pockets present in imprinting material 36a and/or subsequently trapped in the patterned imprinting layer

34, it has been found beneficial to control the composition of fluid in atmosphere 78 and/or the pressure of atmosphere 78.

[0028] Referring to Fig. 9, to facilitate control of atmosphere 78, chuck body 42 is designed to facilitate the passage of fluids proximate to mold 28 and imprint head 18 includes a baffle 100 surrounding template 26. Specifically, baffle 100 extends from imprint head 18, terminating in a nadir 102 that lies in a plane in which a surface 26a lies. In this fashion, mold 28 extends beyond nadir 102 to facilitate contact with region 77. Chuck body 42 includes one or more throughways, two of which are shown as 104 and 106. Apertures 104a and 106a of throughways 104 and 106, respectively, are disposed in a surface of chuck body 42 disposed between template 26 and baffle 100, referred to as a peripheral surface 100a. Throughways 104 and 106 place apertures 104a and 106a in fluid communication with fluid supply system 70. Baffle 100 functions to slow the movement of fluid exiting apertures 104a and 106a away from mold 28. To that end, baffle 100 includes first and second opposed surfaces 102a and 102b. First opposed surface 102a extends from nadir 102 away from substrate 30 and faces template 26. Second opposed surface 102b extends from nadir 102 away from substrate 30 and faces away from mold 28. Although it is not necessary, first opposed surface 102a is shown extending obliquely with respect to second opposing surface 102b. With this configuration, atmosphere 78 may be controlled by introduction or evacuation of fluid through apertures 104a and 106a. However, first and second opposed surfaces 102a and 102b may extend parallel to one another from nadir 102.

[0029] Referring to Figs. 3 and 9, in one embodiment, atmosphere 78 is established so that the transport of the gases present therein through imprinting material 36a in region 77 is increased relative to transport associated with air. The term transport is defined to mean any mechanism by which the propagation of gases through imprinting material 36a is increased, e.g., increased solubility, increased diffusion, increased permeability and the like. To that end, fluid supply system 70 may include a supply of imprinting material 36a or components thereof in vapor form. Under control of processor 25, which is in data communication with fluid supply system 70, imprinting material 36a may be introduced through apertures 104a and 106a to saturate atmosphere 78 with imprinting material 36a. This was found to reduce, if not completely eliminate, the quantity of gases, such as air, trapped in the imprinting layer 34 during imprint processes. This is beneficial as it was found that the presence of air in imprinting layer 34 creates undesirable voids. Alternatively, it was found that by saturating atmosphere 78 with carbon dioxide and/or helium, the quantity of air trapped in imprinting layer 34, shown in Fig. 5, was substantially reduced if not avoided, thereby reducing, if not eliminating, formation of undesirable voids therein. Further, it was found that by employing the atmosphere 78 described above, not only were the number of undesirable voids reduced or eliminated, but the time required to achieve an acceptable minimum level of pattern defects was found to be substantially shorter. It should be understood that a mixture of imprinting material 36a, shown in Fig. 3, carbon dioxide and/or helium may be introduced into

atmosphere 78, shown in Fig. 9, to reduce the quantity of air trapped in imprinting layer 34, shown in Fig. 5.

[0030] Referring to Figs. 9 and 10, a difficulty encountered with respect to introducing fluids was to ensure that the molecules in the fluid streams 104b and 106b exiting apertures 104a and 106a, respectively, traveled to a region of the atmosphere positioned between mold 28 and droplets 36, and before contact of droplets 36 with mold 28. This region of atmosphere 78 is referred to as a processing region 78a. As shown, apertures 104a and 106a are disposed about peripheral surface 100a, which is spaced-apart from processing region 78a. Given that the separation of mold 28 from region 77 is on the order of microns, the ingress of the aforementioned molecules into processing region 78a is difficult to achieve.

[0031] One manner in which to overcome the aforementioned difficulty is to have fluid supply system 70 under control of processor 25 programmed with suitable control software (not shown) to pulse fluid streams 104b and 106b into atmosphere 78 having a desired mixture of molecules, discussed above. In this manner, laminar flow of fluid streams 104b and 106b may be avoided. It is believed that by providing fluid streams 104b and 106b with turbulent flow, the probability will be increased that a sufficient quantity of the molecules contained therein will reach processing region 78a to reduce, if not avoid, the presence of gases being trapped in imprinting layer 34 (not shown). To that end, fluid may be pulsed through both apertures 104a and 106a, concurrently, or sequentially pulsed through the same, i.e., first fluid is introduced through aperture 104a and

subsequently through aperture 106a and then again through 104a, with the process being repeated for a desired time or during the entire imprinting process. Furthermore, the timing of the flow of gas into processing region 78a is important because it is desired that a sufficient quantity of molecules contained therein reach processing region 78a before contact is made between mold 28 and droplets 36.

[0032] Alternatively, fluid may be pulsed through one of the apertures, e.g., aperture 104a, and then evacuated through the remaining aperture, e.g., aperture 106a. In this manner, fluid would be drawn across processing region 78a. It may also be advantageous to pulse the fluid through both apertures 104a and 106a, concurrently, then evacuate through both apertures 104a and 106a concurrently. It is desired, however, that the flow rate of fluid be established to minimize, if not avoid, movement of droplets 36.

[0033] To ensure that the fluids exiting apertures 104a and 106a crosses through processing region 78a, it may be advantageous to concurrently pulse fluid through both apertures 104a and 106a concurrently and then alternately evacuate through one of apertures 104a or 106a. Concurrently introducing the fluid through both apertures 104a and 106a minimizes the time required to saturate atmosphere 78. Alternately evacuating the fluid through one of apertures 104a and 106a ensures that the fluid travels through processing region 78a. For example, a first step would include introducing fluid into atmosphere 78 through both apertures 104a and 106a. A second step would include evacuating the fluid through one of apertures 104a and 106a, e.g., aperture 104a.

Thereafter, at a third step, fluid would be introduced into atmosphere 78 through both apertures 104a and 106a, concurrently. At a fourth step, fluid would be evacuated through one of apertures 104a and 106a that was not employed in the previous step to remove fluid, e.g., aperture 106a. It should be understood that evacuation may occur through one of apertures 104a and 106a, while fluid is being introduced through the remaining aperture of apertures 104a and 106a. Alternatively, evacuation may occur in the absence of a fluid flow into atmosphere 78. The desired result is that fluid ingress into atmosphere 78 and fluid evacuation therefrom occurs so that the desired concentration of fluid is present.

[0034] In another embodiment, a plurality of apertures may be disposed about peripheral surface 100a so that each of the apertures of a pair is disposed opposite one another on opposite sides of template 26. This is shown by aperture pair 104a and 106a being disposed opposite one another on opposite sides of template 26. A second aperture pair is shown as 108a and 110a. Apertures 108a and 110a are disposed opposite one another on opposite sides of template 26.

[0035] As shown, each of apertures 104a, 106a, 108a and 110a, are arranged to lie on a common circle with adjacent apertures being spaced-apart therefrom by 90°. In this manner, each of apertures 104a, 106a, 108a and 110a are arranged to facilitate fluid flow in/out of a different quadrant of chuck body 42. Specifically, aperture 104a facilitates fluid flow in/out of quadrant I; aperture 106a facilitates fluid flow in/out of quadrant II; aperture 108a facilitates fluid flow in/out of quadrant III; and aperture 110a facilitates fluid flow

in/out of quadrant IV. However, any number of apertures may be employed, e.g., more than one per quadrant with differing quadrants having differing numbers of apertures and arranged in any spatial arrangement desired. Each of these arrangements should facilitate introduction and/or evacuation of a plurality of flows of fluid streams into atmosphere 78, with a subset of the plurality of flows being introduced to differing regions about template 26. It is believed that introduction of the multiple flows of fluid streams provides a turbulent flow of fluid in atmosphere 78. This, it is believed, increases the probability that molecules in the fluid streams would reach processing region 78a, shown in Fig. 9. However, fluid flow into atmosphere 78 through each of the apertures 104a, 106a, 108a and 110a and evacuation of fluid from atmosphere 78 therethrough may occur in any manner discussed above.

[0036] Referring to Figs. 9, 10 and 11, in another embodiment, a fluid stream may be introduced through each of apertures 104a, 106a, 108a and 110a sequentially so that a flow cell 112 may be created between template 26 and region 77. Flow cell 112 would facilitate ingress of molecules in the fluid streams into processing region 78a to provide the benefits mentioned above. For example, first a fluid flow may be introduced through aperture 104a and then terminated. After termination of fluid flow through aperture 104a, fluid flow through aperture 106a is commenced to introduce fluid into atmosphere 78. Subsequently, fluid flow through aperture 106a is terminated. After termination of fluid flow through aperture 106a, fluid flow through aperture 108a is commenced to introduce fluid into atmosphere 78.

Fluid flow in through aperture 108a is subsequently terminated. After termination of fluid flow through aperture 108a, fluid flow through aperture 110a is commenced to introduce fluid into atmosphere 78. In this manner, fluid is introduced into atmosphere 78 through a single quadrant at any given time. However, it may be desirable to introduce fluid into more than one quadrant. Although this may frustrate creation of flow cell 112, it is within confines of the present invention.

[0037] Alternatively, sequential introduction and evacuation through apertures 104a, 106a, 108a and 110a may be undertaken to create flow cell 112. This would include introducing fluid through one or more of apertures 104a, 106a, 108a and 110a, concurrently. Subsequently, sequential evacuation may occur through each of apertures 104a, 106a, 108a and 110a to create flow cell 112. For example, fluid may be introduced through all apertures in chuck body 42, concurrently. Thereafter, fluid may be evacuated from each of apertures 104a, 106a, 108a and 110a, one at a time. Before, the concentration in atmosphere 78 of fluid introduced through apertures 104a, 106a, 108a and 110a went below a desired level due to evacuation. The fluid may then be reintroduced through one or all of apertures 104a, 106a, 108a and 110a again and the process repeated to create and/or maintain flow cell 112.

[0038] The embodiments of the present invention described above are exemplary. Many changes and modifications may be made to the disclosure recited above, while remaining within the scope of the invention. Therefore, the scope of the invention should not be limited by the above description, but instead should be

determined with reference to the appended claims along with their full scope of equivalents.

WHAT IS CLAIMED IS:

1. A method for reducing gases present in a layer of viscous liquid deposited on a substrate, said method comprising:

varying a composition of gases proximate to said viscous liquid to increase transport of said gases in said viscous liquid.

2. The method as recited in claim 1 wherein varying further includes increasing a solubility of said gases in said viscous liquid.

3. The method as recited in claim 1 wherein varying further includes increasing diffusion of said gases in said viscous liquid.

4. The method as recited in claim 1, wherein varying further includes increasing permeability of said gases in said viscous liquid.

5. The method as recited in claim 1 wherein varying further includes controlling an atmosphere proximate to said substrate by introducing a fluid, therein, saturated with said viscous liquid.

6. The method as recited in claim 1 further including reducing a pressure of an atmosphere proximate to said substrate.

7. The method as recited in claim 1 wherein varying further includes controlling an atmosphere proximate to said substrate by introducing a fluid,

therein, to increase said transport of said gases in said viscous liquid.

8. The method as recited in claim 6 wherein introducing further includes introducing said fluid selected from a set of fluids consisting of carbon dioxide and helium.

9. A method of introducing a fluid between a mold, disposed on a template, and a substrate, said method comprising:

introducing a flow of said fluid proximate said to template to produce a turbulent flow of said fluid between said substrate and said template to move a portion of said fluid in said flow between said mold and said substrate.

10. The method as recited in claim 9 wherein introducing further includes pulsing said flow of said fluid into a region adjacent to said template and in superimposition with said substrate.

11. The method as recited in claim 9 wherein introducing further includes pulsing said flow of said fluid, with pulsing further including injecting said fluid sequentially through multiple regions at differing positions about a periphery of said template to create a flow cell in an atmosphere located between said mold and said substrate.

12. A system for introducing a flow of a fluid between a mold, disposed on a template, and a substrate, said system comprising:

a fluid supply system; and

a chuck body having a baffle and first and second apertures, said first and second apertures disposed on a surface of said chuck body between said baffle and said template, with said first and second apertures in fluid communication with said fluid supply system to produce a turbulent flow of said fluid between said mold and said substrate.

13. The system as recited in claim 12 wherein said chuck body further includes a plurality of apertures disposed on said surface of said chuck body between said baffle and said template.

14. The system as recited in claim 12 wherein said chuck body further includes a plurality of apertures disposed on said surface of said chuck body between said baffle and said template, with said plurality of apertures including a pair of apertures disposed opposite one another.

15. The system as recited in claim 12 wherein said chuck body further includes a plurality of apertures disposed on said surface of said chuck body between said baffle and said template, with said plurality of apertures lying in a common circle having a plurality of quadrants, with a quadrant of said plurality of quadrants comprising a set of apertures of said plurality of apertures, with differing quadrants of said plurality of

quadrants comprising differing sets of apertures of said plurality of apertures.

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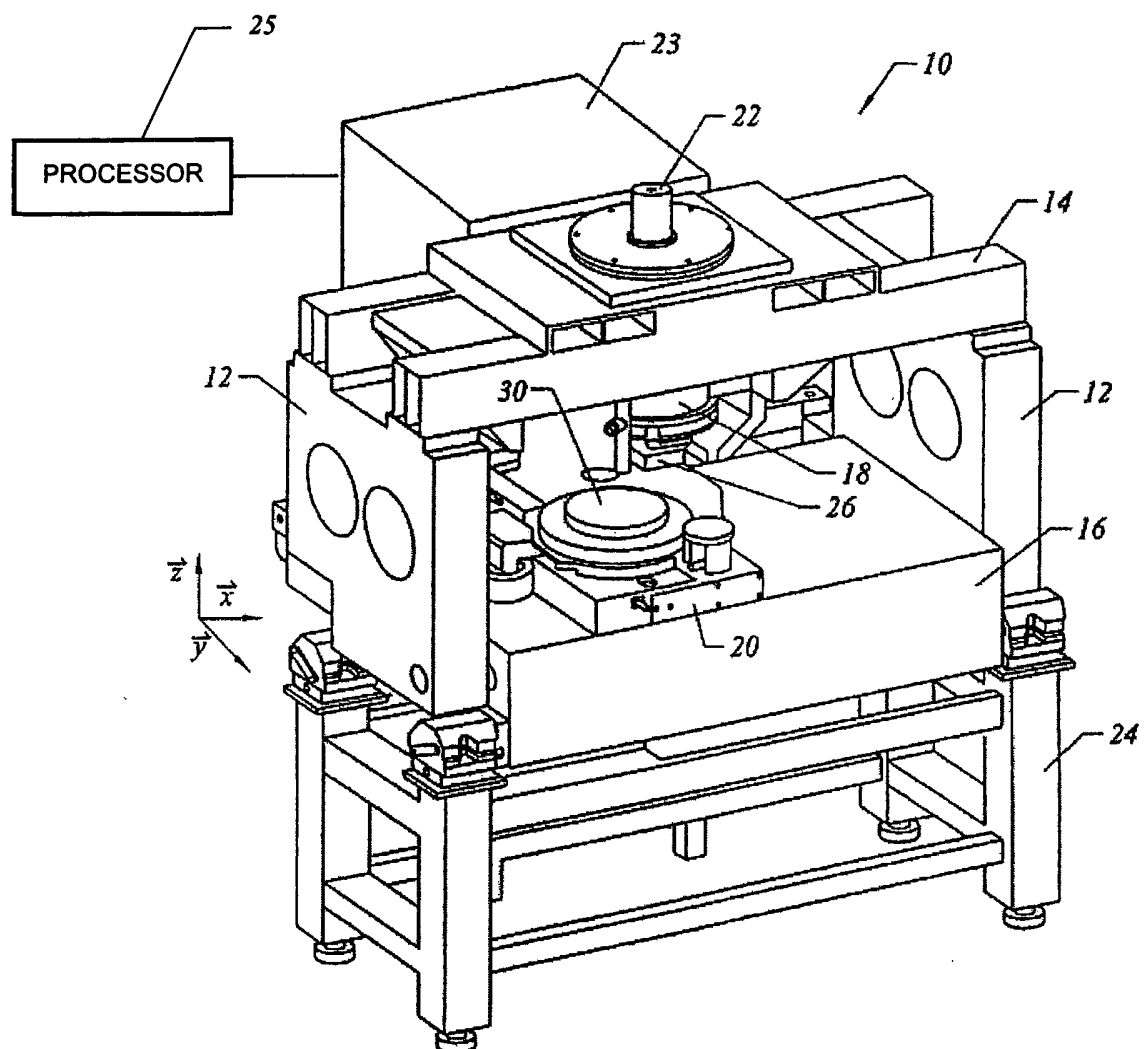


Fig. 1

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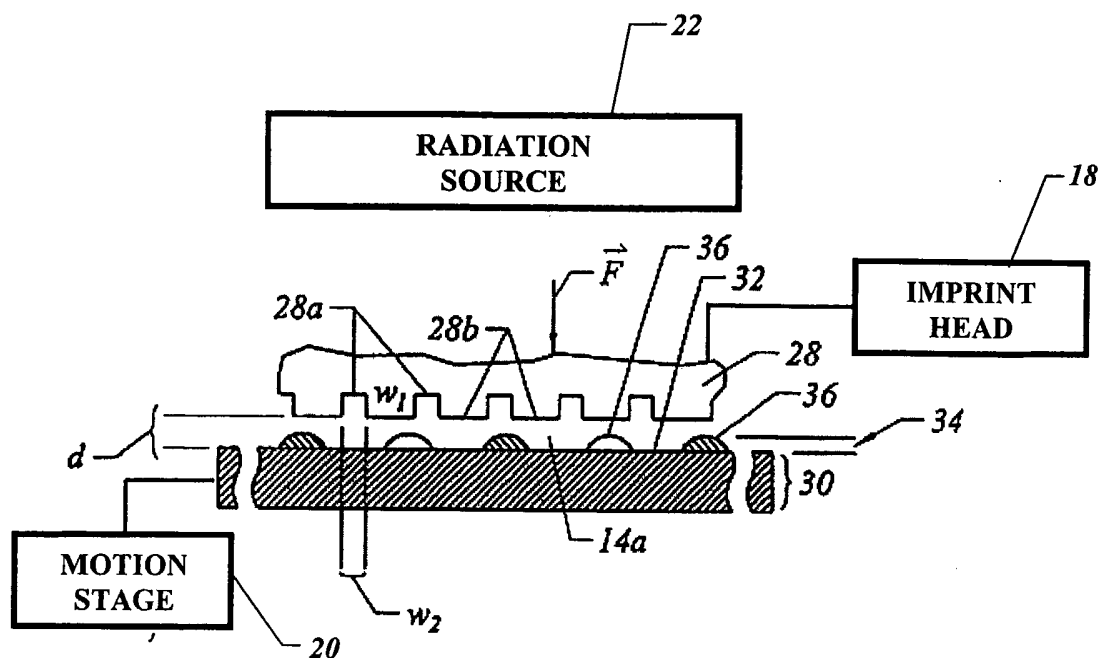


Fig. 2

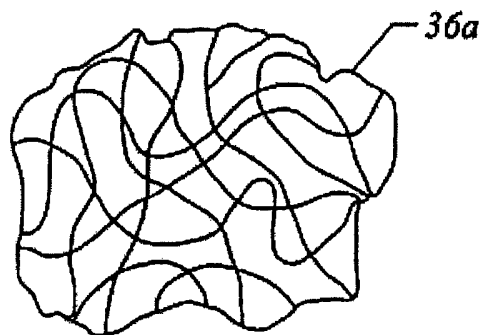


Fig. 3

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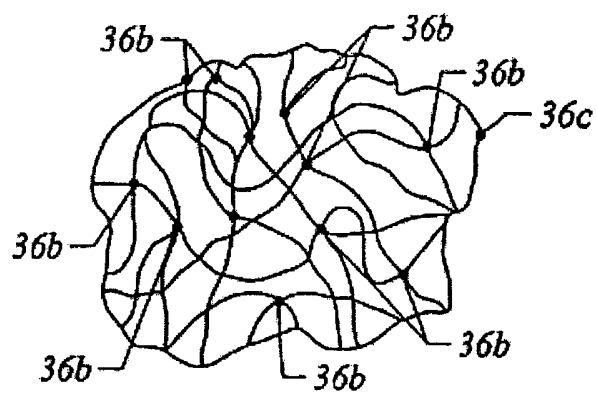


Fig. 4

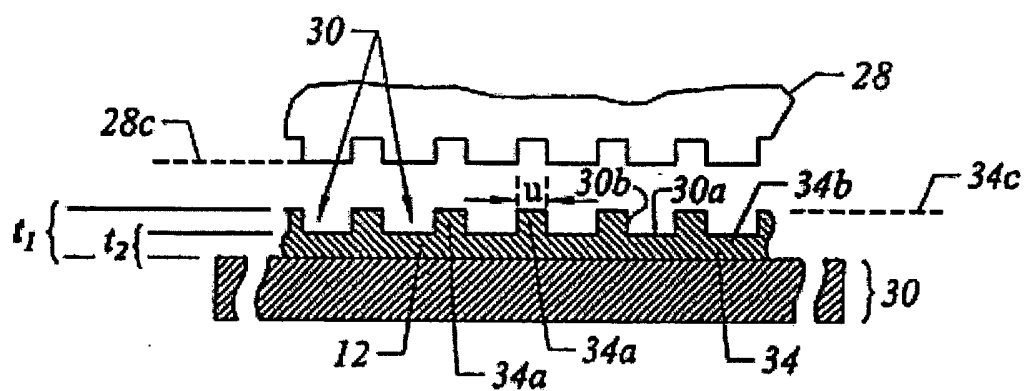


Fig. 5

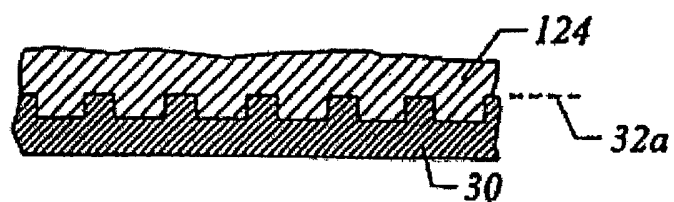


Fig. 6

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